

Taiwan Semiconductor

500mW, NPN Small Signal Transistor

FEATURES

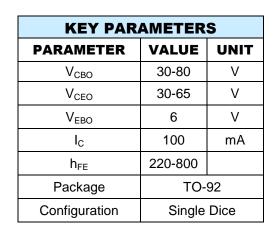
- Low power loss, high efficiency
- Ideal for automated placement
- High surge current capability
- Compliant to RoHS directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- Lighting application
- On-board DC/DC converter

MECHANICAL DATA

- Case: TO-92
- Molding compound meets UL 94 V-0 flammability rating
- Moisture sensitivity level: level 1, per J-STD-020
- Packing code with suffix "G" means green compound (halogen-free)
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 1A whisker test
- Weight: 8mg (approximately)







1. Collector 2.Base 3. Emitter TO-92 Plastic Package

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)					
PARAMETER	SYMBOL	VALUE	UNIT		
Marking code on the device		BC8xxA/B/C (Note 1)			
Power dissipation	P _D	500	mW		

Notes:

1. "xx" is device code from "46" to "50", "MARKING" should follow the "PART NO."



PARAMETER	SYMBOL	VALUE	UNIT	
	BC546		80	
Collector-base voltage, emitter open	BC547,BC550	V _{CBO}	50	V
	BC548,BC549		30	
	BC546		65	
Collector-emitter voltage, base open	BC547,BC550	V _{CEO}	45	V
	BC548,BC549		30	
	BC546		6	
Emitter-base voltage, collector open	BC547,BC550	V _{EBO}	6	V
	BC548,BC549		6	
Collector current	I _C	100	mA	
Peak collector current		I _{CM}	200	mA
Junction temperature		TJ	-65 to +150	°C
Storage temperature		T _{STG}	-65 to +150	°C

PARAMETER	CONDITIONS		SYMBOL	MIN	ТҮР	MAX	UNIT
Collector cutoff current, emitter open	V _{CB} = 30 V		І _{сво}	-	-	15	nA
Emitter cutoff current, collector open	V _{EB} = 5 V		I _{EBO}	-	-	100	nA
Collector-base voltage, $I_C = 1$ emitter open		BC546		80	-	-	V
	I _C = 100 μA	BC547,BC550	V _{CBO}	50	-	-	
		BC548,BC549		30	-	-	
Collector-	Collector-	BC546		65	-	-	
emitter voltage, $I_c = 10 \text{ mA}$ base open	BC547,BC550	V _{CEO}	45	-	-	V	
		BC548,BC549		30	-	-	1
Emitter-base		BC546		6	-	-	1
	I _E = 100 μΑ	BC547,BC550	V _{EBO}	6	-	-	V
		BC548,BC549		6	-	-	1
		Current gain group :A		110	-	220	1
	DC current V_{CE} = 5 V,gain I_C = 2 mA	В	h _{FE}	200	-	450	1
gain		C		420	-	800	1



ORDERING INFORMATION					
PART NO.	PACKING CODE	PACKING CODE SUFFIX(*)	PACKAGE	PACKING	
BC5xxA/B/C (Note 1)	A1	G	TO-92	4K / Ammo	
	B1			5K / Bulk	

Notes:

1. "xx" is device code from "46" to "50"

*: optional available

EXAMPLE					
EXAMPLE P/N	PART NO.	PACKING CODE	PACKING CODE SUFFIX	DESCRIPTION	
BC546A A1G	BC546A	A1	G	Green compound	



Taiwan Semiconductor

CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

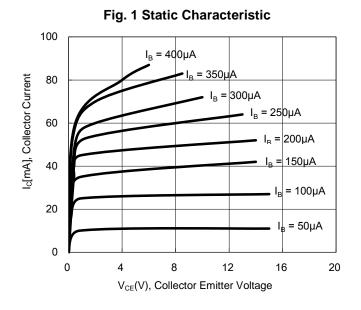


Fig. 2 Transfer Characteristic 100 V_{CE}=5V Ic(mA), Collector Current 10 1 0 0.0 0.2 0.4 0.6 0.8 1.0 1.2 V_{BE}(V), Base Emitter Voltage

Fig. 3 DC Current Gain

10

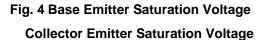
1000

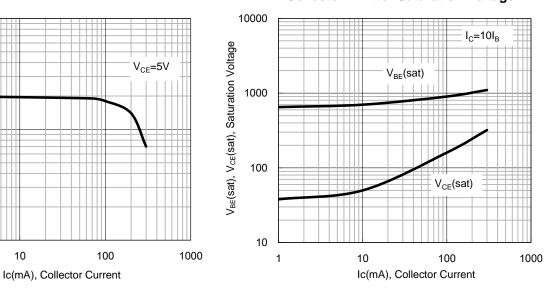
100

10

1

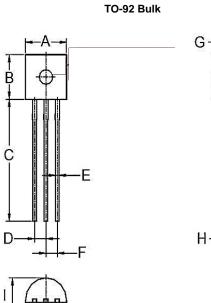
h_{FE}, DC Current Gain

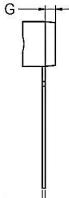






PACKAGE OUTLINE DIMENSION

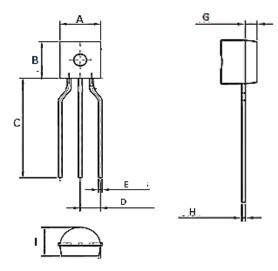




Γ

D 114			Unit(inch)		
DIM.	Min	Max	Min	Max	
A	4.40	5.10	0.173	0.201	
В	4.30	4.70	0.169	0.185	
С	12.50	14.50	0.492	-	
D	1.17	1.37	0.046	0.054	
E	0.35	0.55	0.014	0.022	
F	1.17	1.37	0.046	0.054	
G	0.59	1.40	0.023	0.055	
н	0.29	0.51	0.011	0.020	
I	3.30	4.10	0.130	0.161	

TO-92 Ammo



DIM.	Unit	(mm)	Unit(inch)		
DIN.	Min Max		Min	Max	
А	4.30	4.70	0.169	0.185	
В	4.30	4.70	0.169	0.185	
С	12.50	-	0.492	-	
D	2.20	2.80	0.087	0.110	
E	0.35	0.55	0.014	0.022	
G	1.00	1.20	0.039	0.047	
н	0.29	0.51	0.011	0.020	
I	3.30	3.70	0.130	0.146	

Τ Unit(mm) Τ Unit(inch)



BC546A/B/C - BC550A/B/C

Taiwan Semiconductor

Notice

Specifications of the products displayed herein are subject to change without notice. TSC or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, to any intellectual property rights is granted by this document. Except as provided in TSC's terms and conditions of sale for such products, TSC assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of TSC products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify TSC for any damages resulting from such improper use or sale.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Bipolar Transistors - BJT category:

Click to view products by Taiwan Semiconductor manufacturer:

Other Similar products are found below :

619691C MCH4017-TL-H BC546/116 BC557/116 BSW67A NTE158 NTE187A NTE195A NTE2302 NTE2330 NTE63 C4460 2SA1419T-TD-H 2SA1721-O(TE85L,F) 2SA2126-E 2SB1204S-TL-E 2SC5488A-TL-H 2SD2150T100R SP000011176 FMMTA92QTA 2N2369ADCSM 2SC2412KT146S 2SC5490A-TL-H 2SD1816S-TL-E 2SD1816T-TL-E CMXT2207 TR CPH6501-TL-E MCH4021-TL-E US6T6TR NJL0281DG 732314D CMXT3906 TR CPH3121-TL-E CPH6021-TL-H 873787E IMZ2AT108 UMX21NTR EMT2T2R MCH6102-TL-E FP204-TL-E NJL0302DG 2N3583 2SA1434-TB-E 2SC3143-4-TB-E 2SD1621S-TD-E NTE103 30A02MH-TL-E NSV40301MZ4T1G NTE101 NTE13